

1-Gbit, 2-Gbit, 2112-byte/1056-word page, 1.8 V/3 V, NAND flash ...

Manufacturers	STMicroelectronics, Inc
Package/Case	TSOP48
Product Type	Memory
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for NAND01GW3B2CN6E or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

NAND01GW3B2CN6E is a specific model of NAND flash memory produced by Toshiba. Here are some of its features:

Features

Memory size: 1 gigabit

Interface: NAND Flash 8-bit

Supply voltage: 2.7 V to 3.6 V

Operating temperature range: -40°C to 85°C

Package type: TSOP-48

Application

Storing operating system and application code in smartphones and tablets

Storing music, videos, and photos on portable media players and digital cameras

Storing data in USB flash drives and memory cards for use in various devices



Related Products



[NAND01GW3B2BN6F](#)

STMicroelectronics, Inc
TSOP-48



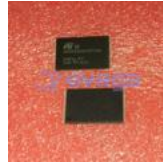
[NAND512W3A2BN6E](#)

STMicroelectronics, Inc
TSOP-1-48



[NAND512W3A2CN6E](#)

STMicroelectronics, Inc
TSOP-48



[NAND08GW3B2CN6](#)

STMicroelectronics, Inc
TSOP48



[NAND08GW3B2CN6E](#)

STMicroelectronics, Inc
TSOP48



[M29W640GB-70NA6](#)

STMicroelectronics, Inc
TSOP-48



[NAND512W3A2BZA6](#)

STMicroelectronics, Inc
TFBGA63



[NAND01GW3B2BN6E](#)

STMicroelectronics, Inc
TSOP-48